## P-Channel 30-V (D-S) MOSFET

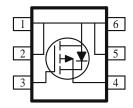
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

| • | Low r <sub>DS(on)</sub> provides higher efficiency and |
|---|--|
|   | extends battery life                                   |

- Low thermal impedance copper leadframe TSOP-6 saves board space
- · Fast switching speed
- High performance trench technology

| PRODUCT SUMMARY |                                |          |  |  |
|-----------------|--------------------------------|----------|--|--|
| $V_{DS}(V)$     | $r_{DS(on)}(O)$                | $I_D(A)$ |  |  |
| -30             | 0.056 @ V <sub>CS</sub> =-10V  | -4.0     |  |  |
| -30             | 0.086 @ V <sub>CS</sub> =-4.5V | -3.4     |  |  |





| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED) |                                     |     |            |       |  |  |
|--|-------------------------------------|-----|------------|-------|--|--|
| Parameter  |                                     |     | Maximum    | Units |  |  |
| Drain-Source Voltage   |                                     |     | -30        | V     |  |  |
| Gate-Source Voltage  |                                     |     | ±20        | v     |  |  |
| Continuous Drain Current <sup>a</sup>                                    | $T_A=25^{\circ}C$                   | T., | -4.0       |       |  |  |
| Continuous Drain Current   | $T_A=25^{\circ}C$ $T_A=70^{\circ}C$ | ъ   | -3.2       | A     |  |  |
| Pulsed Drain Current <sup>b</sup>  |                                     |     | ±20        |       |  |  |
| Continuous Source Current (Diode Conduction) <sup>a</sup>                |                                     |     | -1.7       | A     |  |  |
| D D a  | $T_A=25^{\circ}C$                   | D   | 2.0        | W     |  |  |
| Power Dissipation <sup>a</sup>   | $T_A=25^{\circ}C$ $T_A=70^{\circ}C$ | ГБ  | 1.3        | ٧٧    |  |  |
| Operating Junction and Storage Temperature Range                         |                                     |     | -55 to 150 | °C    |  |  |

| THERMAL RESISTANCE RATINGS               |              |            |       |      |  |  |
|--|--------------|------------|-------|------|--|--|
| Parameter                                | Symbol       | Maximum    | Units |      |  |  |
|  | t <= 5 sec   | D          | 62.5  | °C/W |  |  |
| Maximum Junction-to-Ambient <sup>a</sup> | Steady state | $R_{THJA}$ | 110   | °C/W |  |  |

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## Notes

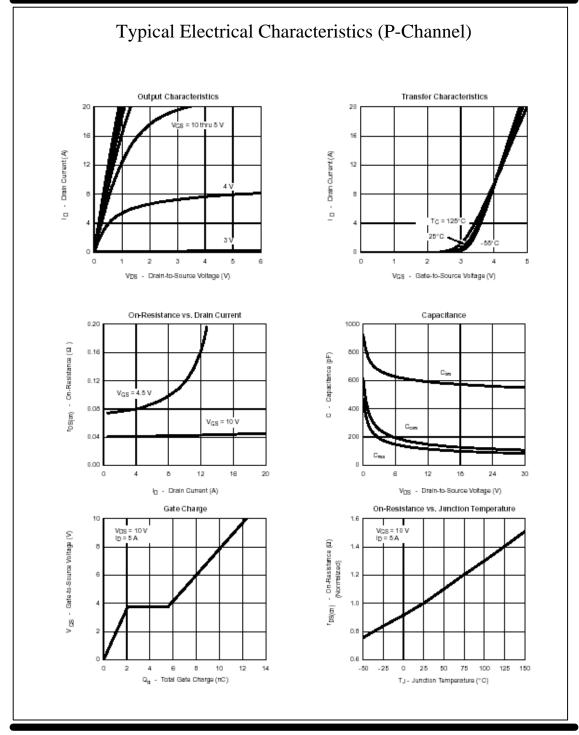
- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

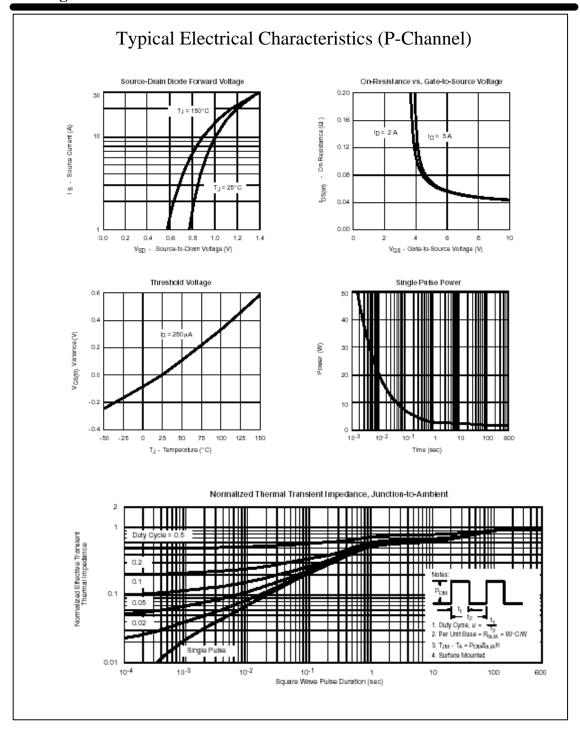
| SPECIFICATIONS (T <sub>k</sub> = 25°C UNLESS OTHERWISE NOTED) |                     |   |        |      |      |        |  |
|---|---------------------|---|--------|------|------|--------|--|
| D   | C                   | T (C 191  | Limits |      |      | TT .*4 |  |
| Parameter   | Symbol              | Symbol Test Conditions  |        | Тур  | Max  | Unit   |  |
| Static  |                     |   |        |      |      |        |  |
| Gate-Threshold Voltage  | V <sub>GS(th)</sub> | $V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$                                | -1     |      |      |        |  |
| Gate-Body Leakage   | IGSS                | $V_{DS} = 0 V, V_{GS} = \pm 20 V$   |        |      | ±100 | nA     |  |
| a court bio   | Inna                | $V_{DS}=-16  \text{V},  V_{GS}=0  \text{V}$                               |        |      | -1   | uA     |  |
| Zero Gate Voltage Drain Current                               | Idss                | $V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$  |        |      | -5   |        |  |
| On-State Drain Current  | I <sub>D(on)</sub>  | $V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$                          | -20    |      |      | Α      |  |
| D : G . C D : . A   | IDS(on)             | $V_{GS} = -10 \text{ V}, I_D = -4.0 \text{ A}$                            |        |      | 56   |        |  |
| Drain-Source On-Resistance                                    |                     | $V_{GS} = -4.5 \text{ V}, \text{ Ib} = -3.4 \text{ A}$                    |        |      | 86   | mO     |  |
| Forward Tranconductance <sup>A</sup>                          | gfs                 | $V_{DS} = -5 \text{ V}, I_{D} = -3.4 \text{ A}$                           |        | 10   |      | S      |  |
| Diode Forward Voltage   | Vsd                 | $I_S = 1.3 \text{ A}, V_{GS} = 0 \text{ V}$                               |        | -0.8 |      | V      |  |
| Dynamic <sup>b</sup>  |                     |   |        |      |      |        |  |
| Total Gate Charge   | Qg                  | V 20VVV 10V   |        | 6.4  |      |        |  |
| Gate-Source Charge  | Qgs                 | $V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V},$ $I_{D} = -40 \text{ A}$ |        | 1.9  |      | пС     |  |
| Gate-Drain Charge   | $Q_{gd}$            | ID=-4.0 A   |        | 2.5  |      |        |  |
| Turn-On Delay Time  | t <sub>d(on)</sub>  |   |        | 7    |      |        |  |
| Rise Time   | tr                  | $V_{DD}$ =-20 V, $R_L$ =6 O , $I_D$ =-1 A,                                |        | 10   |      |        |  |
| Turn-Off Delay Time   | t <sub>d(off)</sub> | $V_{GEN} = -10V$  |        | 30   |      | ns     |  |
| Fall-Time   | $t_{\mathrm{f}}$    |   |        | 22   |      | Ī      |  |

## Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

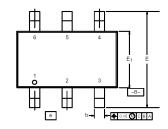
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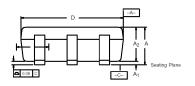


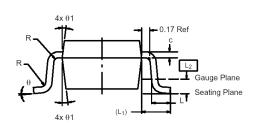


## Package Information

TSOP-6: 6LEAD







|                | MILLIMETERS   |      |      | INCHES     |           |       |
|----------------|---------------|------|------|------------|-----------|-------|
| Dim            | Min           | Nom  | Max  | Min        | Nom       | Max   |
| Α              | 0.91          | -    | 1.10 | 0.036      | =         | 0.043 |
| A <sub>1</sub> | 0.01          | _    | 0.10 | 0.0004     | -         | 0.004 |
| A <sub>2</sub> | 0.84          | _    | 1.00 | 0.033      | 0.038     | 0.039 |
| b              | 0.30          | 0.32 | 0.45 | 0.012      | 0.013     | 0.018 |
| С              | 0.10          | 0.15 | 0.20 | 0.004      | 0.006     | 0.008 |
| D              | 2.95          | 3.05 | 3.10 | 0.116      | 0.120     | 0.122 |
| E              | 2.70          | 2.85 | 2.98 | 0.106      | 0.112     | 0.117 |
| E <sub>1</sub> | 1.55          | 1.65 | 1.70 | 0.061      | 0.065     | 0.067 |
| е              | 1.00 BSC      |      |      | 0.0394 BSC |           |       |
| L              | 0.35          | _    | 0.50 | 0.014      | _         | 0.020 |
| L <sub>1</sub> | 0.60 Ref      |      |      |            | 0.024 Ref |       |
| L <sub>2</sub> | 0.25 BSC      |      |      |            | 0.010 BSC |       |
| R              | 0.10          | _    | _    | 0.004      | -         | _     |
| θ              | 0°            | 4°   | 8°   | 0°         | 4°        | 8°    |
| θ1             | 7° Nom 7° Nom |      |      |            |           |       |

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